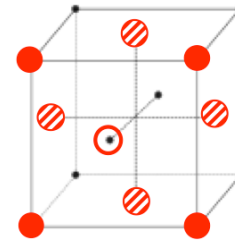


Question 1 Basic crystal properties

Face-centred cubic (fcc)

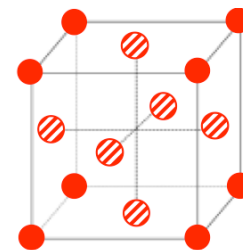
Nearest neighbour atoms:

If you look at the circled atom, the nearest neighbours are on the same plane (filled circles, 4 atoms) as well as on the neighbouring planes (circles with oblique lines, 4 atoms on the plane behind and another 4 atoms on that behind (not shown), 8 atoms in total). As a result, the nearest neighbours are 12 atoms.



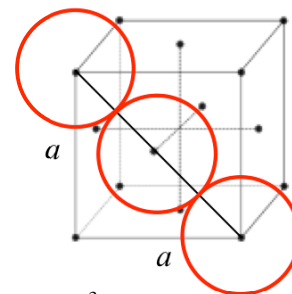
Atoms in a unit cell:

In a unit cell, filled atoms are shared with 8 neighbouring unit cells ($1/8 \times 8 = 1$), and circles with oblique lines are shared with 2 neighbouring unit cells ($1/2 \times 6 = 3$). As a sum, a unit cell contains 4 atoms.



Filling rate:

As shown in the right figure, 3 atoms are connected with each other along the diagonal axis in a unit cell plane, indicating that the radius of the atoms is $\sqrt{2}a/4$. Therefore, the filling rate is calculated to be



$$\frac{(\text{atoms in unit cell}) \times (\text{atom sphere volume})}{(\text{unit cell volume})} = \frac{4 \times \frac{4}{3} \pi r^3}{a^3} = \frac{4 \times \frac{4}{3} \pi \left(\frac{\sqrt{2}a}{4}\right)^3}{a^3} = \frac{2\sqrt{2}}{12} \pi = 74\%.$$

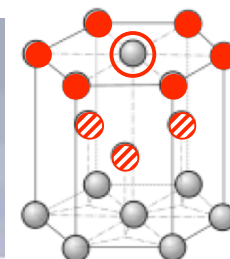
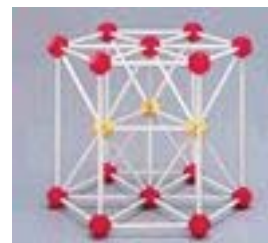
Hexagonal close-packed (hcp)

Nearest neighbour atoms:

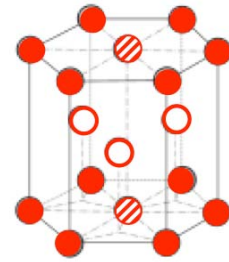
If you look at the circled atom, the nearest neighbours are on the same plane (filled circles, 6 atoms) as well as on the neighbouring planes (circles with oblique lines, 3 atoms on the plane below and another 3 atoms on that above (not shown), 6 atoms in total). As a result, the nearest neighbours are 12 atoms.

Atoms in a unit cell:

In a unit cell, filled atoms are shared with 6 neighbouring unit cells ($1/6 \times 12 = 2$),



circles with oblique lines are shared with 2 neighbouring unit cells ($1/2 \times 2 = 1$), and open circles are not shared with the other unit cells (3 atoms). As a sum, a unit cell contains 6 atoms.



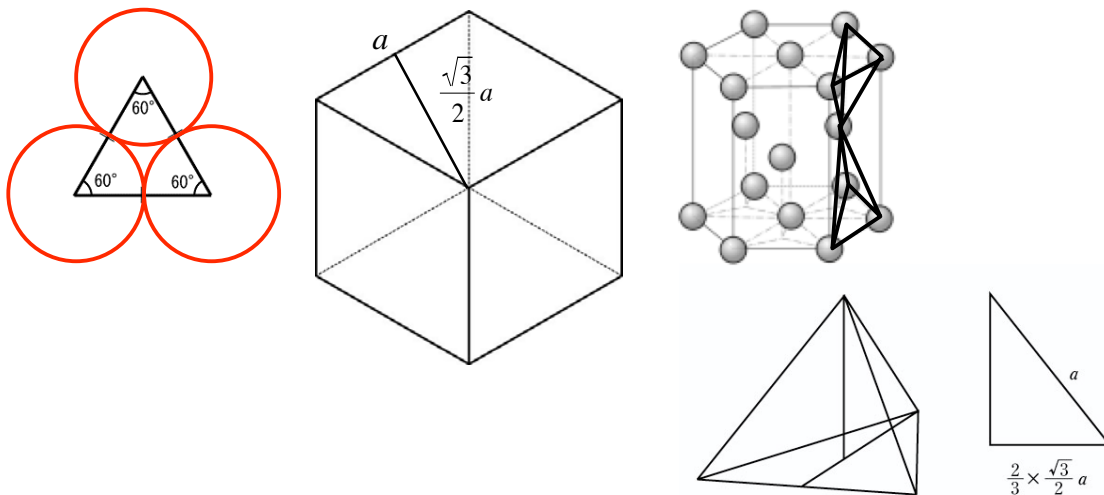
Filling rate:

As shown in the bottom figure, 3 atoms are connected with each other in an equilateral triangle plane in the bottom unit cell plane, indicating that the radius of the atoms is $a/2$.

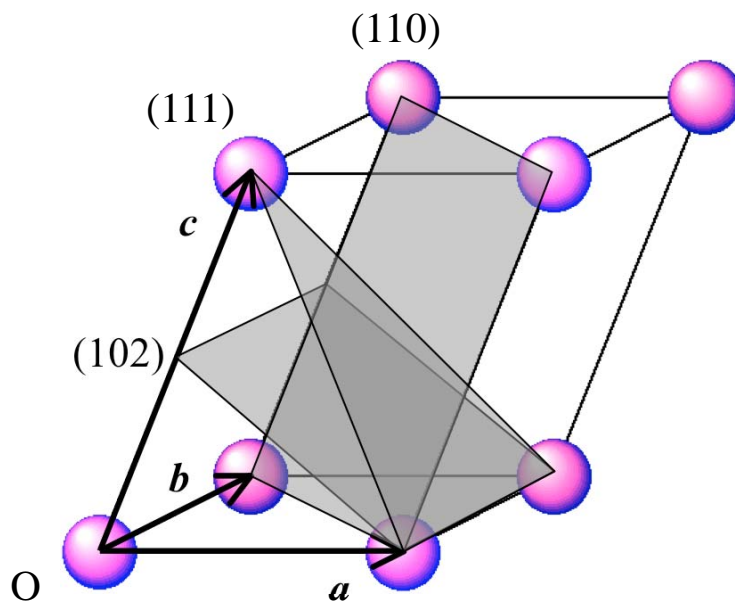
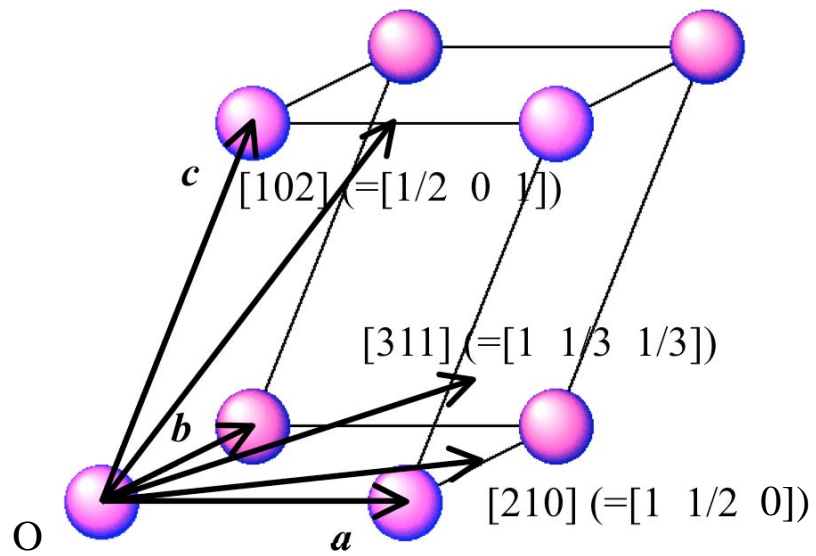
Here, the area of this equilateral triangle is $(1/2) \times (\sqrt{3}a/2) \times a$, resulting the surface area of the bottom unit cell plane to be $(1/2) \times (\sqrt{3}a/2) \times a \times 6$. Since the hcp unit cell contains a pair of regular tetrahedrons in the vertical direction, the unit cell height is calculated to be $\sqrt{a^2 - (2/3) \times (\sqrt{3}a/2)} \times 2$. Therefore, the filling rate is calculated to be as follows:

$$\frac{(\text{atoms in unit cell}) \times (\text{atom sphere volume})}{(\text{unit cell volume})} = \frac{6 \times \frac{4}{3} \pi r^3}{\left(\frac{1}{2} \times \frac{\sqrt{3}a}{2} \times a\right) \times 6 \times \sqrt{a^2 - \left(\frac{2}{3} \frac{\sqrt{3}a}{2}\right)^2} \times 2}$$

$$= \frac{\pi a^3}{3\sqrt{2}a^3} = \frac{1}{3\sqrt{2}} \pi = 74\%.$$



Question 2 Miller indices



Question 3 Relaxation time

Equation of motion of an electron with resistive force mv/τ is

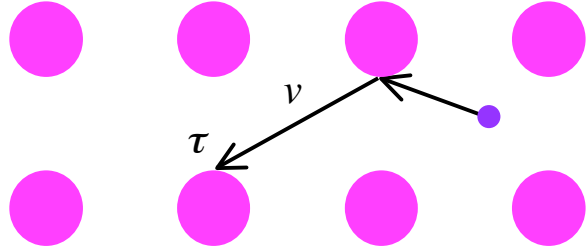
$$m \frac{dv}{dt} = -qE - \frac{m}{\tau} v$$

$$\frac{dv}{dt} + \frac{1}{\tau} v = -\frac{qE}{m}$$

Multiplying $e^{t/\tau}$ for both sides,

$$e^{t/\tau} \frac{dv}{dt} + \frac{1}{\tau} e^{t/\tau} v = -\frac{qE}{m} e^{t/\tau}$$

$$e^{t/\tau} \frac{dv}{dt} + \left(\frac{d}{dt} e^{t/\tau} \right) v = -\frac{qE}{m} e^{t/\tau}$$



By using integration by parts: $\frac{d}{dx} f(x)g(x) = \frac{df(x)}{dx} g(x) + f(x) \frac{dg(x)}{dx}$,

$$\frac{d}{dt} \left(e^{t/\tau} v \right) = -\frac{qE}{m} e^{t/\tau}$$

$$\therefore e^{t/\tau} v = -\int \frac{qE}{m} e^{t/\tau} dt + C$$

Therefore,

$$\begin{aligned} v &= -\frac{qE}{m} e^{-t/\tau} \left\{ \int e^{t/\tau} dt + C' \right\} \\ &= -\frac{qE}{m} e^{-t/\tau} \left(\tau e^{t/\tau} + C' \right) \\ &= -\frac{q\tau E}{m} \left(1 - C'' e^{-t/\tau} \right) \end{aligned}$$

For $v=0$ at $t=0$,

$$v = -\frac{q\tau E}{m} \left(1 - e^{-t/\tau} \right)$$

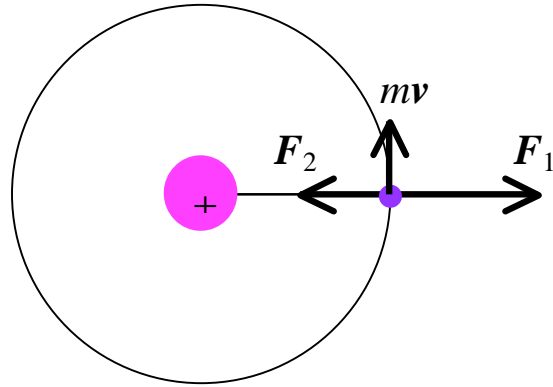
Question 4 Electron potential energy

Centrifugal force F_1 is

$$F_1 = \frac{mv^2}{r}$$

Coulomb force F_2 is

$$F_2 = -\frac{Zq^2}{4\pi\epsilon_0 r^2}$$



For a stable electron rotation, $|F_1|=|F_2|$ and hence,

$$\frac{mv^2}{r} = \frac{Zq^2}{4\pi\epsilon_0 r^2}$$

Accordingly, electron kinetic energy is obtained as

$$\frac{1}{2}mv^2 = \frac{1}{2} \frac{Zq^2}{4\pi\epsilon_0 r}$$

Here, potential energy V is defined as $-\frac{dV}{dr} = F_2$, and therefore,

$$\begin{aligned} V &= \int_r^\infty \left(-\frac{dV}{dr} \right) dr = \int_r^\infty F_2 dr \\ &= \int_r^\infty \left(-\frac{Zq^2}{4\pi\epsilon_0 r^2} \right) dr \\ &= \left[-\frac{Zq^2}{4\pi\epsilon_0} \left(-\frac{1}{r} \right) \right]_r^\infty \\ &= 0 - \frac{Zq^2}{4\pi\epsilon_0 r} \\ &= -\frac{Zq^2}{4\pi\epsilon_0 r} \\ &\propto -\frac{A}{r} \end{aligned}$$

(A: constant)